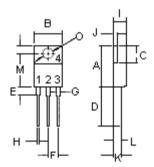
## **Darlington Transistors**





### Features:

- Designed for general-purpose amplifier and low speed switching applications.
- Collector-Emitter sustaining voltage-V<sub>CEO(sus)</sub> = 60V (Minimum) TIP120, TIP125 80V (Minimum) - TIP121, TIP126 100V (Minimum) - TIP122, TIP127.
- Collector-Emitter saturation voltage- $V_{CE(sat)}$  = 2.0V (Maximum) at  $I_C$  = 3.0A.
- Monolithic construction with built-in-base-emitter shunt resistors.



Pin 1. Base

- 2. Collector
- 3. Emitter
- 4. Collector (Case)

	Minimum	Maximum
Α	14.68	15.31
В	9.78	10.42
С	5.01	6.52
D	13.06	14.62
Е	3.57	4.07
F	2.42	3.66
G	1.12	1.36
Н	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
М	2.48	2.98
0	3.70	3.90

Dimensions : Millimetres

NPN	PNP
TIP120	TIP 125
TIP121	TIP 126
TIP122	TIP 127

5.0 Ampere
Darlington
Complementary Silicon
Power Transistors
60 - 100 Volts
65 Watts



## **Maximum Ratings**

Characteristic	Symbol	TIP120 TIP121		TIP122	Unit	
Characteristic	Symbol	TIP125	TIP126	TIP127	Uiiit	
Collector-Emitter Voltage	V <sub>CEO</sub>	60	80	100		
Collector-Base Voltage	V <sub>CBO</sub>	1 00	80	100	V	
Emitter-Base Voltage	V <sub>EBO</sub>	5.0				
Collector Current -Continuous	I <sub>C</sub>	5.0		Α		
-Peak	I <sub>CM</sub>	8.0			_ ^	
Base Current	Ι <sub>Β</sub>	120			mA	
Total Power Dissipation at T <sub>C</sub> = 25°C	P <sub>D</sub>	65		W		
Derate above 25°C	' D	0.52			W/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150		°C		

### **Thermal Characteristics**

Characteristic	Symbol	Maximum	Unit
Thermal Resistance Junction to Case	Rθjc	1.92	°C/W

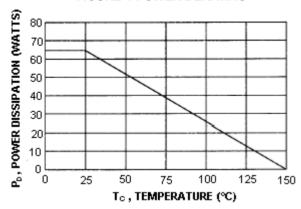


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## **Darlington Transistors**



FIGURE-1 POWER DERATING



## Electrical Characteristics (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Minimum	Maximum	Unit
OFF Characteristics			1		
Collector-Emitter Sustaining Voltage	ge (1)				
$(I_C = 30 \text{mA}, I_B = 0)$	$A I_0 = 0$ TIP120 TIP125		60		V
	TIP121, TIP126	V <sub>CEO(sus)</sub>	80	-	V
	TIP122, TIP127		100		
Collector Cut off Current					
$(V_{CE} = 30V, I_B = 0)$	TIP120, TIP125	1		0.5	
$(V_{CE} = 40V, I_{B} = 0)$	TIP121, TIP126	I <sub>CEO</sub>	-	0.5	
$(V_{CE} = 50V, I_B = 0)$	TIP122, TIP127			0.5	
Collector Cut off Current					^
$(V_{CB} = 60V, I_B = 0)$	TIP120, TIP125		-	0.2	mA
$(V_{CB} = 80V, I_B = 0)$	TIP121, TIP126	I <sub>CBO</sub>		0.2	
$(V_{CB} = 100V, I_B = 0)$	TIP122, TIP127			0.2	
Collector Cut off Current		,		0.0	
$(V_{EB} = 5.0V, I_C = 0)$		I <sub>EBO</sub>	-	2.0	
ON Characteristics (1)			1		
DC Current Gain					
$(I_C = 0.5A, V_{CE} = 3.0V)$		h <sub>FE</sub>	1000	-	-
$(I_C = 3.0A, V_{CE} = 3.0V)$			1000		
Collector-Emitter Saturation Voltage	је				
$(I_C = 3.0A, I_B = 12mA)$	$V_{CE(sat)}$	-	2.0		
$(I_C = 5.0A, I_B = 20mA)$				4.0	V
Base-Emitter On Voltage		V	_	2.5	
$(I_C = 3.0A, V_{CE} = 3.0V)$		V <sub>BE(on)</sub>	-	2.5	
Dynamic Characteristics					
Small-Signal Current Gain		h <sub>fe</sub>	4.0	_	_
$(I_C = 3.0A, V_{CE} = 4.0V, f = 1.0MH)$	<u>z)</u>	''te	4.0		
Output Capacitance					
$(V_{CB} = 10V, I_E = 0, f = 0.1MHz)$	TIP120, TIP121, TIP122	C <sub>ob</sub>	_	300	pF
	TIP125, TIP126, TIP127			250	þi

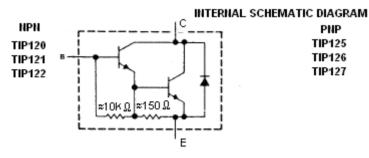
<sup>(1)</sup> Pulse Test : Pulse Width =  $300\mu s$ , Duty Cycle  $\leq 2.0\%$ 



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PNP TIP125 TIP126 TIP127

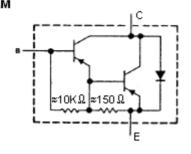


FIGURE - 2 SWITCHING TIME

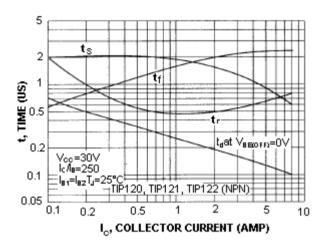


FIGURE - 3 SWITCHING TIME

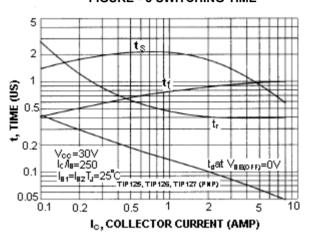
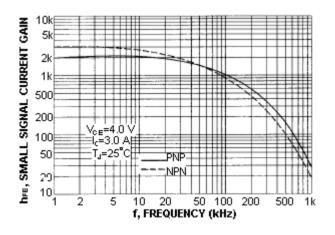
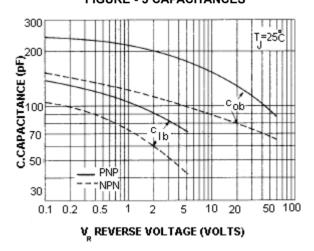


FIGURE - 4 SMALL SIGNAL CURRENT GAIN



**FIGURE - 5 CAPACITANCES** 



multicomp

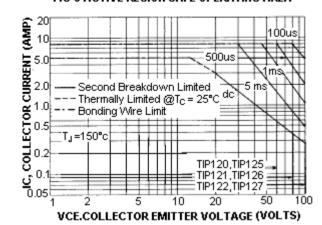
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## **Darlington Transistors**



#### FIGURE - 6 ACTIVE REGION SAFE OPERATING AREA

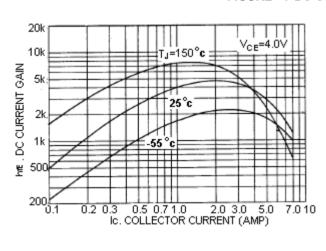
#### FIG-6 ACTIVE REGION SAFE OPERATING AREA



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate  $I_{C-}V_{CE}$  limits of the transistor that must not be subjected to greater dissipation than the curves indicate.

The data of Figure - 6 is based on  $T_{J(PK)}$  = 150°C; $T_c$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_J(PK) \le 150$ °C, At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

#### FIGURE - 7 DC CURRENT GAIN



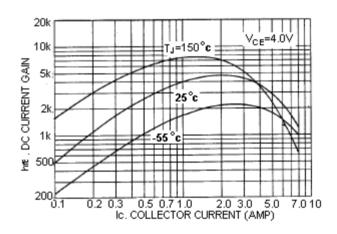
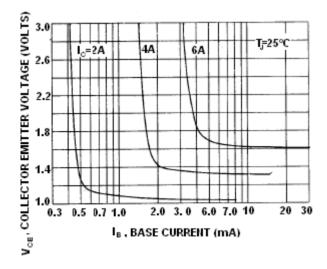
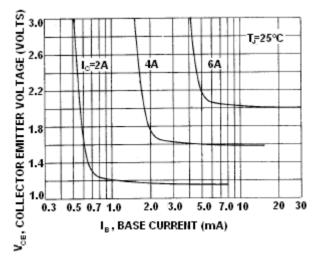


FIGURE - 8 COLLECTOR SATURATION REGION





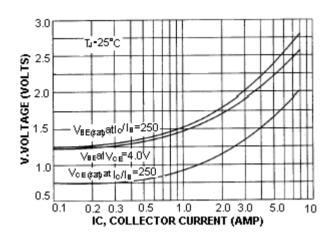
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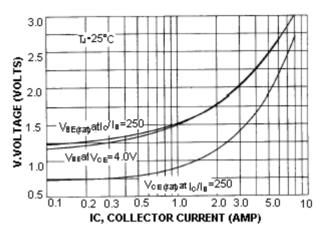
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## **Darlington Transistors**



### FIGURE - 9 "ON" VOLTAGES





## **Specifications**

I <sub>C</sub> (maximum) V		h <sub>FE</sub> minimum	P <sub>tot</sub> at 25°C	Package -	Part N	umber
	at I <sub>c</sub> = 3A	W W	Fackage	NPN	PNP	
	60				TIP120	TIP125
5	80	1000	65	TO-220	TIP121	TIP126
100				TIP122	TIP127	

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## **Darlington Transistors**



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